



SEVENTH SEMESTER B.TECH. (E & C) DEGREE END SEMESTER EXAMINATION

DECEMBER 2018/JANUARY 2019

SUBJECT: ANALOG AND MIXED SIGNAL DESIGN (ECE - 4013)

TIME: 3 HOURS

MAX. MARKS: 50

Instructions to candidates

- Answer **ALL** questions.
- Missing data may be suitably assumed.

- 1A. Design the 4th order 455 kHz unity gain Butterworth LPF with normalized transfer function given by

$$H_d(s) = \frac{1}{s^4 + 2.613s^3 + 3.414s^2 + 2.813s + 1}$$

use equal transconductance approach and assume $g_m = 30.1 \mu S$. Draw the circuit diagram and mention the advantages and disadvantages of 4th order LPF with unity feedback gain.

- 1B. Draw the circuit diagram of triple cascode current mirror and derive the expression for output resistance. Consider the triple cascode current sink, assume all transistors operating in saturation region with $I_d = 10 \mu A$, $V_{DS} = 50V$, amplification factor $g_{m0} = 50$. Find the value of output resistance. Neglect the bulk effect

(5+5)

- 2A. With neat diagram explain mixed signal layout strategy used to improve the performance of analog circuitry.

- 2B. With neat diagram explain first order sigma delta modulator and implement using switched capacitor technique. State how the resolution of ADC can be enhanced without using an external ADC.

(5+5)

- 3A. Consider a 1:8 current sink circuit, assume that the lengths are identical. Find the ratio error, if W_1 is $(5 \pm 0.05) \mu m$ and W_2 is $(40 \pm 0.05) \mu m$. Find the ratio error if this current amplifier with ΔW correction, by considering 8 MOSFETs in parallel.

- 3B. Consider a 2 integrator loop distributive feedback with one feedback factor and show all the possible biquad transfer function.

(3+7)

- 4A. Draw the circuit of parasitic insensitive integrator using switched capacitor technique and derive the expression for transfer function.

- 4B. Using switched capacitor technique implement the passive RC first order low pass filter so that product of RC is 1msec and 3-dB frequency is 159Hz.

4C. With neat diagram explain compensation of finite bandwidth effects in Operational Trans conductance Amplifiers.

(4+3+3)

5A. The differential amplifier shown in Figure 5A should achieve a differential gain of 40 with a power consumption of 2mW. All the transistors operate with the same V_{OV} . Find (W/L) of all transistors, V_{g3} , V_{g4} , V_{g5} . Assume $\mu_n C_{ox} = 400 \mu A/V^2$, $\mu_p C_{ox} = 100 \mu A/V^2$, $\lambda_n = 0.1/V$, $\lambda_p = 0.2/V$ and $V_{tn} = |V_{tp}| = 0.4V$

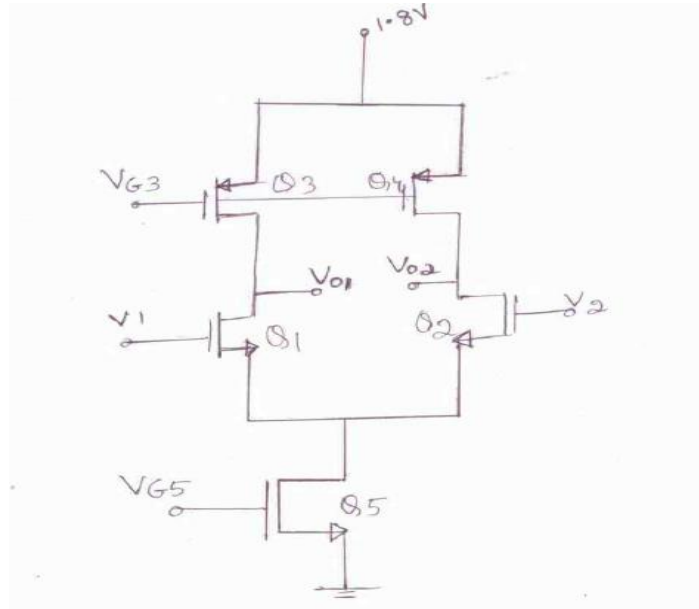


Figure 5A

5B. Give Operational Trans conductance Amplifier implementation of lossy integrator in differential mode and derive the transfer function.

(5+5)